Properties of Nitrogen-Vacancy Centers in Diamond: The Group Theoretic Approach

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Properties of nitrogen-vacancy centers in diamond: group theoretic approach

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We present a procedure that makes use of group theory to analyze and predict the main properties of the negatively charged nitrogen-vacancy (NV) center in diamond. We focus on the relatively low temperatures limit where both the spin-spin and spin-orbit effects are important to consider. We demonstrate that group theory may be used to clarify several aspects of the NV structure, such as ordering of the singlets in the \((e^2)\) electronic configuration, the spin-spin and the spin-orbit interactions in the \((ae)\) electronic configuration. We also discuss how the optical selection rules and the response of the center to electric field can be used for spin-photon entanglement schemes. Our general formalism is applicable to a broad class of local defects in solids. The present results have important implications for applications in quantum information science and nanomagnetometry.

I. INTRODUCTION

During the past few years nitrogen-vacancy (NV) centers have emerged as promising candidates for a number of applications [1-4] ranging from high spatial resolution imaging [5] to quantum computation [6]. At low temperatures, the optical transitions of the NV center become very narrow and can be coherently manipulated, allowing for spin-photon entanglement generation [7] for quantum communication and all optical control [8]. A detailed understanding of the properties of this defect is critical for many of these applications. Several studies have addressed this issue both experimentally [9, 10] and theoretically [11, 12]. Furthermore, other atom-like defects can potentially be engineered in diamond [13] and other materials with similar or perhaps better
properties suitable for the desired application. Therefore, it is of immediate importance to develop a formalism to analyze and predict the main properties of defects in solids.

Here we present a formalism based on a group theoretical description. While we focus on describing the nitrogen-vacancy center in diamond, our formalism can be applied to any point defect in solid state physics. Our method takes advantage of the symmetry of the states to properly treat the relevant interactions and their symmetries. We apply group theory to find out not only the symmetry of the eigenstates but also their explicit form in terms of orbital and spin degrees of freedom. We show that this is essential to build an accurate model of the NV center. In particular, we analyze the effect of the Coulomb interaction and predict that the ordering of the triplet and singlet states in the ground state configuration is \( \{3A_2, 1E, 1A_1\} \) and that the distance between them is on the order of the exchange term of the electron-electron Coulomb energy. This ordering has been debated over the last few years and our results agree with recent \textit{ab initio} calculations carried in bulk diamond [14].

Our method is also used to analyze important properties of the center such as polarization selection rules. The explicit form of the states allows us to identify a particularly useful lambda-type transition that was recently used for spin-photon entanglement generation[7]. We also consider perturbations that lower the symmetry of a point defect, such as strain and electric field and how they affect the polarization properties. We also show that the non-axial spin-orbit interaction discussed in Ref. [15] does not mix the eigenstates of the center in a given multiplet. Instead, we find that the electron spin-spin interaction is responsible for the spin state mixing of the excited state as a result of the lack of inversion symmetry of the center. Finally, we analyze the effect of electric fields via the inverse piezoelectric effect and compare our results with experimental observations. We show that this effect can be used to tune the polarization properties of optical transitions and the wavelength of emitted photons, which is of direct importance for photon-based quantum communication between NV centers. Our study clarifies important properties of NV centers and provides the foundation for coherent interaction between electronic spins and photons in solid state.

Our manuscript is organized as follows. In Section II we present a general group theoretical formalism to calculate the electronic or hole representation of a point defect for a given crystal field symmetry and number of electrons contained in the defect. Next, we use group theory and the explicit form of the states to analyze the effect of the Coulomb interaction between electrons (Section III) and spin-spin and spin-orbit interactions for the NV center (Sections V and IV, respectively). Next, we analyze the selection rules of the unperturbed defect in Section VI. Finally,
II. STATE REPRESENTATION

We are particularly interested in quasi-static properties of defects in crystals where the complex electronic structure can be observed spectroscopically. In this limit one can apply the Born-Oppenheimer approximation to separate the many-body system of electrons and nuclei. This approximation relies on the fact that nuclei are much slower than electrons. In this approximation the nuclei are represented by their coordinates and the physical quantities of the electrons depend on these coordinates as (external) fixed parameters. A defect in a crystal breaks down the translational symmetry reducing the symmetry of the crystal to rotations and reflections. These symmetries form a point group which in general is a subgroup of the point group of the lattice. The loss of translational symmetry indicates that the Bloch-states are no longer a good approximation to describe the point defect. In fact, some states can be very well localized near the point defect. These defect states are particularly important in semiconductors and insulators when they appear within the fundamental band gap of the crystal.

In the tight binding picture, the electron system of the diamond crystal may be described as the sum of covalent-type interactions between the valence electrons of two nearest neighbor atoms. When defects involve vacancies, the absence of an ion will break bonds in the crystal, producing unpaired electrons or dangling bonds, $\sigma_i$, which to leading order can be used to represent the single electron orbitals around the defect. The particular combination of dangling bonds that form the single electron orbitals $\{\varphi_r\}$ is set by the crystal field of the defect and can be readily calculated by projecting the dangling bonds on each irreducible representation (IR) of the point group of the defect\[16\],

$$\varphi_r = P^{(r)} \sigma_i = \frac{l_r}{h} \sum_e \chi_e^{(r)} R_e \sigma_i,$$  

where $P^{(r)}$ is the projective operator to the IR $r$, $\chi_e^{(r)}$ is the character of operation $R_e$ (element) for the IR $r$, $l_r$ is the dimension of the IR $r$, and $h$ is the order of the group (number of elements). A detailed application of Eq. (1) for the case of the NV center can be found in Appendix A. There are two non-degenerate totally symmetric orbitals $a_1(1) \text{ and } a_2(1)$ that transform according to the one-dimensional IR $A_1$, and there are two degenerate states $\{e_x, e_y\}$ that transform according to the two-dimensional IR $E$. At this stage, group theory does not predict the energy order of these states. However a simple model of the electron-ion Coulomb interaction can be used to qualitatively
obtain the ordering of the levels \[17\]. In Appendix A we model the effect of this interaction on the single electron orbitals, \(\varphi_r\), for the case of the NV center and find that the ordering of the states (increasing in energy) is \(a_1(1), a_1(2)\) and \(\{e_x, e_y\}\). Indeed, \textit{ab initio} density functional theory (DFT) calculations revealed \[18, 19\] that the \(a_1(1)\) and \(a_1(2)\) levels fall lower than the \(e_x\) and \(e_y\) levels, which demonstrates the strength of group theory for \textit{qualitative} predictions.

Once the symmetry and degeneracy of the orbitals are determined, the dynamics of the defect is set by the number of electrons available to occupy the orbitals. The orbitals with higher energy will predominantly set the properties of the defect. The spin character of the defect will be determined by the degeneracy of the orbitals and the number of electrons in them, leading to net spins \(S = \{0, 1, 2, \ldots\}\) if this number is even and \(S = \left\{\frac{1}{2}, \frac{3}{2}, \ldots\right\}\) if odd.

In the case of the negatively charged NV center, each carbon atom contributes one electron, the nitrogen (as a donor in diamond) contributes two electrons, and an extra electron comes from the environment \[19\], possibly given by substitutional nitrogens \[20\]. The ground state configuration consists of four electrons occupying the totally symmetric states and the remaining two electrons pairing up in the \(\{e_x, e_y\}\) orbitals. In this single particle picture, the excited state configuration can be approximated as one electron being promoted from the \(a_1(2)\) orbital to the \(e_{x,y}\) orbitals \[18\].

If two more electrons were added to any of these configurations, the wavefunction of the defect would be a singlet with a totally symmetric spatial wavefunction, equivalent to the state of an atom with a filled shell \[21, 22\]. Therefore, the electronic configuration of this defect can be modeled by two holes occupying the orbitals \(e_{x,y}\) in the ground state \((e^2\) electronic configuration) and one hole each in the orbitals \(a_1(2)\) and \(e_{x,y}\) for the excited state \(ae\) electronic configuration). A third electronic configuration, \(a^2\), can be envisioned by promoting the remaining electron from the orbital \(a_1(2)\) to the orbitals \(e_{x,y}\). Hole and electron representations are totally equivalent and it is convenient to choose the representation containing the smallest number of particles. If a hole representation is chosen, some care must be taken, as some interactions reverse their sign, such as the spin-orbit interaction \[21\]. In what follows, we choose a hole representation containing two particles (instead of an electron representation containing four particles), since it is more convenient to describe the physics of the NV center. However, the analysis can be applied to electrons as well.

The representation of the total \(n\)-electron wavefunction, including space and spin degrees of freedom, is given by the direct product of the representation of each hole \(\Gamma_{hn}\) and its spin \(\Gamma_\Psi = \Pi_n \left(\Gamma_{hn} \otimes D_{\frac{1}{2}}\right)\), where \(D_{\frac{1}{2}}\) is the representation for a spin \(\frac{1}{2}\) particle in the corresponding point group. The reduction or block diagonalization of the representation \(\Gamma_\Psi\) gives the eigenstates of the
hamiltonian associated with the crystal field potential and any interaction that remains invariant under the elements of the point group in question. These interactions include spin-orbit, spin-spin and Coulomb interactions, as well as expansions, contractions, and stress where their axes coincide with the symmetry axis of the defect. The eigenstates can be found by projecting any combination of the two electron wavefunction onto the irreducible representations of the group \([16, 23]\),

\[
Ψ^r = \frac{1}{\hbar} \sum_e \chi_e^{(r)} R_e \varphi_1 R_e \varphi_2,
\]

where \(\varphi_1\) can be any of the orbitals in Eq. (1) and the subindex \(i\) refers to the hole \(i\). In the case of the NV center, it is illustrative to note that the spin representation for the two particles can be reduced to \(D_{1/2} \otimes D_{1/2} = A_1 + A_2 + E\), where \(A_1\) corresponds to the singlet state, and \(A_2\) and \(E\) to the triplet state with zero and non-zero spin projections, respectively. A list of the eigenstates and their symmetries for the two hole representation can be found in Table I for the ground state \(\langle e^2 \rangle\) and the excited state \(\langle ae \rangle\). For completeness, we include the doubly excited state \(\langle a^2 \rangle\) electronic configuration although this state is not optically accessible in the excitation process of the NV center in experiments. Note that each electronic configuration might have singlet and triplet states. The calculation performed to obtain Table I is similar to the calculation made to find the eigenstates when two spin particles are considered. However, in this case one should use the Wigner coefficients of the corresponding irreducible representation of the point group under consideration.

Group theory can predict why the hyperfine interaction with the nuclear spin of the nitrogen in the excited state is more than an order of magnitude larger than in the ground state for both nitrogen species: the non-zero spin density in the ground state wavefunction of the NV center is mostly concentrated in the orbitals \(e_{x,y}\), which have no overlap with the nitrogen atom. On the other hand, in the excited state, when one electron is promoted from the \(a_1(2)\) orbital to one of the \(e_{x,y}\) orbitals, the non-zero spin density comes now from unpaired electrons occupying the orbitals \(a_1(2)\) and \(e_{x,y}\). As the orbital \(a_1(2)\) is partially localized on the nitrogen atom, a sizable contact term interaction between the electronic spin and the nuclear spin of the nitrogen is expected \([19, 24, 25]\).

Up to now, eigenstates inside a given electronic configuration have the same energy, but the inclusion of the electron-electron Coulomb interaction will lift the degeneracy between triplets and singlets. The resulting energy splitting can be of the order of a fraction of an eV and it is analyzed for the ground state configuration of the NV center in Section III. Furthermore, the degeneracy of triplet states is lifted by spin-orbit and spin-spin interactions of the order of GHz, where the
crystal field plays an important role. These interactions will be treated in sections IV and V.

TABLE I: Partner functions of each IR for the direct product of two holes. The first column shows the electronic configuration and in parenthesis their triplet (T) or singlet (S) character. The last column shows the name of the state given in this paper and their symmetry. \( \alpha (\beta) \) stands for \( \uparrow (\downarrow) \) and \( E_{\pm} = |ae_{\pm} - e_{\pm}a\rangle \), where \( e_{\pm} = \mp (e_x \pm ie_y) \), \( |X\rangle = (|E_{\pm} - |E_{\pm}\rangle)/2 \) and \( |Y\rangle = (|E_{\pm} + |E_{\pm}\rangle)i/2 \).

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III. ORDERING OF SINGLET STATES

For a given electronic configuration, the most relevant interaction is the electron-electron Coulomb interaction, which is minimized when electrons are configured in an antisymmetric spatial configuration. As the total wavefunction must be antisymmetric for fermionic particles, the spin configuration must be symmetric. As a result, the state with the largest multiplicity lies lower in energy. This analysis, known as the first Hund’s rule, predicts that the ground state of the NV center should be the triplet \( 3A_2 \) state. We now address the question related to the order of singlets in the ground state electronic configuration \( e^2 \). The order of singlet states has a great significance in understanding the spin-flipping fluorescence of the NV center, and \textit{ab initio} DFT calculations were unable to address this issue properly due to the many-body singlet states. Since we have the
explicit form of the wavefunctions, we can work out the ordering of the singlets in a given electronic
configuration by analyzing the expectation value of the Coulomb interaction, which can be written
in the general form,

\[ C_{abcd} = \int dV_1 dV_2 a^*(r_1) b^*(r_2) V(|r_1 - r_2|) c(r_1) d(r_2). \]

Using this expression we find that in the ground state electronic configuration \((e^2)\), the Coulomb
interactions for these states are

\[
\begin{align*}
C(3A_2) &= (C_{xyxy} - C_{zyyx} - C_{yxxx} + C_{yxyy}) / 2 \\
C(1E_1) &= (C_{xyxy} + C_{zyyx} + C_{yxxx} + C_{yxyy}) / 2 \\
C(1E_2) &= (C_{xxxx} - C_{xyyy} - C_{yyxx} + C_{yyyy}) / 2 \\
C(1A_1) &= (C_{xxxx} + C_{xyxy} + C_{yyxx} + C_{yyyy}) / 2,
\end{align*}
\]

where \(x, y\) correspond to \(e_x, e_y\) states. From this set of equations we find that the spacing between
the singlets \(1A_1\) and \(1E_2\) is equal to the spacing between the singlet \(1E_1\) and the ground state
\(3A_2\), i.e., \(C(1A_1) - C(1E_2) = C(1E_1) - C(3A_2) = C_{xyyy} + C_{yyxx} \equiv 2e\), where the difference is
the exchange energy. In addition, as \(1E_1\) and \(1E_2\) belong to the same IR \(E\), it can be shown
that \(C(1E_2) = C(1E_1)\) (see Appendix B). Under this consideration, the ordering of the states is
\(\{3A_2, 1E, 1A_1\}\) with relative energies \(\{0, 2e, 4e\}\). It should be noted that, in this case, the most
symmetric state has higher energy since the Coulomb interaction between two electrons is repulsive.
This picture might be modified by the following effect. Since the Coulomb interaction transforms
as the totally symmetric IR, the matrix elements between states with the same symmetry are
non-zero. The states \(1E(e^2)\) and \(1E(ae)\) can couple via the Coulomb interaction, increasing the
gap between them. A similar effect happens with the states \(1A_1(e^2)\) and \(1A_1(a^2)\). In Eq. (3) we
did not take into account the effect of the other electrons present in the system. Nevertheless, our
basic results here serve as a qualitative estimate for the energy of levels and provides useful insight
into the structure of the NV center. The results of a very recent calculations based on many-body
perturbation theory (MBPT) [14] supports our conclusion.

\[ IV. \ SPIN-ORBIT \ INTERACTION \]

In the previous section the electronic spin did not directly enter into our considerations. For
instance, the energy of the \(m_S = 0, \pm 1\) sublevels of the \(3A_2\) ground state would have exactly the
same energy. However, if the electronic spin is taken into account, one can infer from Table I
that in general the \( m_S = 0 \) and \( m_S = \pm 1 \) projections transform as functions of different IRs. For example, in the ground state \(^3\!A_2\), the \( m_S = 0 \) projection transforms as the IR \( A_1 \), while the \( m_S = \pm 1 \) projections transform as the IR \( E \). This implies that the projections do not share the same eigenenergies of the system. The spin-spin and spin-orbit interactions may result in splitting of these orbitally degenerate states.

The spin-orbit interaction lifts the degeneracy of multiplets that have non-zero angular momentum, and is also responsible for transitions between terms with different spin states \[^{[21]}\]. It is a relativistic effect due to the relative motion between electrons and nuclei. In the reference frame of the electron, the nuclear potential, \( \phi \), produces a magnetic field equal to \( \nabla \phi \times \mathbf{v}/c^2 \). In SI units, this interaction is given by

\[
H_{SO} = \frac{1}{2} \frac{\hbar}{c^2 m_e^2} \left( \nabla V \times \mathbf{p} \right) \cdot \left( \frac{\mathbf{s}}{\hbar} \right),
\]

where \( V = e\phi \) is the nuclear potential energy, \( m_e \) is the electron mass and \( \mathbf{p} \) is the momentum.

The presence of the crystal field breaks the rotational symmetry of this interaction. Since \( \phi \) is produced by the nuclear potential, it transforms as the totally symmetric representation \( A_1 \), and therefore \( \nabla V = (V_x, V_y, V_z) \) transforms as a vector, where \( V_i = \partial V/\partial x_i \). Since \( \mathbf{p} \) also transforms as a vector, it is possible to identify the IRs to which the orbital operator components \( \vec{O} = \nabla V \times \mathbf{p} = (V_y p_z - V_z p_y, V_z p_x - V_x p_z, V_x p_y - V_y p_x) \) belong. In \( C_{3v} \), the components of \( \nabla V \) and \( \mathbf{p} \) transform as \((E_1, E_2, A_1)\) and therefore \( \vec{O} \) transforms as the IRs \((E_2, E_1, A_2) = (E, A_2)\). The non-zero matrix elements of the orbital operators \( O_i \) in the basis \( \{a, e_x, e_y\} \) can be determined by checking if \( (\varphi_i, O_k, \varphi_j) \supset A_1 \) and are shown in Table \( \text{II} \) where \( A = \langle e_y | O_x | a \rangle \) and \( B = \langle e_x | O_z | e_y \rangle \) (for simplicity we denote by \( a \) the \( a_1(2) \) orbital state ). In this case, the spin-orbit interaction can be written in terms of the angular momentum operators \( l_i \) and takes the following form:

\[
H_{SO} = \lambda_{xy} (l_x s_x + l_y s_y) + \lambda_z l_z s_z,
\]

where \( \lambda_{x,y}(\lambda_z) \) denotes the non-axial (axial) strength of the interaction. In a system with \( T_d \) or spherical symmetry, \( A = B \) and the usual form \( (\mathbf{S} \cdot \mathbf{L}) \) of the spin-orbit interaction is recovered.

It is also useful to think about \( e_{\pm} \) as \( p_{\pm} \) orbitals and \( a_1(2) \) as a \( p_z \) orbital, where the angular momentum operators satisfy \( l_{\pm} a_1(2) \propto e_{\pm} \ \[^{[26]}\].

Once it is known how the spin-orbit interaction acts on the orbitals, \( e_x, e_y \) and \( a \), it is possible to calculate the effect of this interaction on the 15 states given in Table \( \text{I} \) An important effect is the splitting in the excited state triplet between the states \( A_1, A_2 \) and \( E_x, E_y \) and between states
TABLE II: Matrix elements for orbital operators in the $C_{3v}$ point group. For the $T_d$ symmetry group or spherically symmetric potentials, $A = B$.

\[
\begin{array}{cccc}
O_x & |e_x\rangle & |e_y\rangle & |a\rangle \\
\langle e_x| & 0 & 0 & 0 \\
\langle e_y| & 0 & 0 & -iA \\
\langle a| & 0 & -iA & 0 \\
\end{array} \quad \begin{array}{cccc}
O_y & |e_x\rangle & |e_y\rangle & |a\rangle \\
\langle e_x| & 0 & 0 & -iA \\
\langle e_y| & 0 & 0 & 0 \\
\langle a| & iA & 0 & 0 \\
\end{array} \quad \begin{array}{cccc}
O_z & |e_x\rangle & |e_y\rangle & |a\rangle \\
\langle e_x| & 0 & iB & 0 \\
\langle e_y| & -iB & 0 & 0 \\
\langle a| & 0 & 0 & 0 \\
\end{array}
\]

$E_x, E_y$ and $E_1, E_2$ [11]. The spin-orbit interaction can be written as,

\[ H_{SO} = \lambda_z (|A_1\rangle \langle A_1| + |A_2\rangle \langle A_2| - |E_1\rangle \langle E_1| - |E_2\rangle \langle E_2|), \] (6)

in the excited state triplet manifold $\{A_1, A_2, E_x, E_y, E_1, E_2\}$. Another effect, relevant when treating non-radiative transitions, is that the axial part of the spin-orbit interaction ($\lambda_z$) links states with $m_s = 0$ spin projections among states of the same electronic configuration, while the non-axial part ($\lambda_{x,y}$) links states with non-zero spin projections with singlets among different electronic configurations. In Figure 1 we show the states linked by the axial and the non-axial parts of the spin-orbit interaction, for which non-radiative transitions might occur. In addition to the well known transition between $A_1(\text{ae}) \rightarrow 1^1A_1(\text{e}^2)$, we find that this interaction might also link $E_{1,2}(\text{ae}) \rightarrow 1^1E_{1,2}(\text{e}^2)$ and in particular $E_{x,y} \rightarrow 1^1E_{x,y}(\text{ae})$. The latter transition may play an important role, as recent ab initio calculations have shown that the singlets $1^1E_{x,y}$ might lie very close in energy to the excited state triplet [14]. In our model, the non-axial part of the spin-orbit interaction, $\lambda_{x,y}(l_+s_- + l_-s_+)$, does not mix the states of the excited state triplet with different spin projections because the raising and lower operators, $l_-$ and $l_+$, link states of different electronic configurations. In particular, this interaction cannot mix the states of the excited state triplet because the mixing is suppressed by the large energy gap that separates different electronic configurations.

We have numerically evaluated the ratio between the axial part and transverse part of spin-orbit, $\lambda_z/\lambda_{xy} = B/A = 0.75$ using the functions $e_x$ and $e_y$ and $a_1(2)$ from ab initio calculations (see Appendix E). This suggest that if the axial part of spin-orbit is 5.5 GHz [10], the non-axial part should be on the order of $\lambda_{xy} = 7.3$ GHz and only couples singlets with triplets states as shown in Figure 1. We have also numerically confirmed the structure of Table II with three digits of precision in units of GHz (see Appendix E).
V. SPIN-SPIN INTERACTION

The spin-spin interaction between electrons is usually not present in systems with spherical symmetry, due to the traceless character of the magnetic dipole-dipole interaction. However, if the electron wavefunction is not spherically distributed, this interaction does not average out. Here we describe its effect on the excited state triplet of the NV center and we provide a numerical estimation of its strength. The spin-spin interaction can be written (in SI units) as,

$$ h_{ss} = -\frac{\mu_0 g^2 \beta^2}{4\pi} \frac{1}{r^3} \left( 3(s_1 \cdot \hat{r})(s_2 \cdot \hat{r}) - s_1 \cdot s_2 \right),$$

where $s_i = \frac{1}{2} [\sigma_x, \sigma_y, \sigma_z]$ are the spin operators of particle $i$ and $\sigma_j$ ($j = x, y, z$) are the Pauli matrices, $\beta$ is the Bohr magneton, $g$ is the Landé-factor for the electron and $\mu_0$ is the magnetic permeability of free space \cite{27}. In order to analyze the effect of this interaction in the defect it is useful to write the spatial and spin parts separately in terms of the irreducible representations of the point group. Then, it is straightforward to express this interaction in terms of the eigenstates of the defect (see Appendix C),

$$ H_{ss} = \Delta (|A_1\rangle\langle A_1| + |A_2\rangle\langle A_2| + |E_1\rangle\langle E_1| + |E_2\rangle\langle E_2|)$$

$$ -2\Delta (|E_x\rangle\langle E_x| + |E_y\rangle\langle E_y|)$$

$$ +2\Delta' (|A_2\rangle\langle A_2| - |A_1\rangle\langle A_1|)$$

$$ \Delta'' (|E_1\rangle\langle E_y| + |E_y\rangle\langle E_1| - i|E_2\rangle\langle E_x| + i|E_x\rangle\langle E_2|),$$

where the gaps between the $m_s = \pm 1$ and $m_s = 0$ projections and between $A_1$ and $A_2$ states are given by

$$ 3\Delta = 3\frac{\mu_0 g^2 \beta^2}{4\pi} \left\langle X \left| \frac{1 - 3\hat{z}^2}{4r^3} \right| X \right\rangle = 3\frac{1}{4} D_{zz},$$

$$ 4\Delta' = 4\frac{\mu_0 g^2 \beta^2}{4\pi} \left\langle X \left| \frac{3\hat{x}^2 - 3\hat{y}^2}{4r^3} \right| X \right\rangle = D_{x^2-y^2},$$

while the mixing term is given by

$$ \Delta'' = \frac{\mu_0 g^2 \beta^2}{4\pi} \left\langle X \left| \frac{3\hat{z}^2}{\sqrt{2}r^3} \right| X \right\rangle.$$ (11)

Figure 2 shows the effect of spin-orbit and spin-spin interactions on the excited state manifold. In particular, we find that the state $A_2$ has higher energy than the state $A_1$ ($2\Delta' > 0$), contrary to previous estimations \cite{11, 28}. In addition, we find that the spin-spin interaction $\Delta''$ mixes states with different spin-projections. This effect is the result of the lack of inversion symmetry of the NV
center and it is not present in systems with inversion symmetry such as free atoms or substitutional atoms in cubic lattices. This does not contradict group theoretical estimates as the mixed states transform according to the same IR (e.g. the $E_1$ and $E_y$ states both transform according to the IR $E_1$, see Table I).

We estimated these parameters using a simplified model consisting of the dangling bonds given in Figure 6 (in the Appendix) for the three carbons and the nitrogen atom around the vacancy. The dangling bonds are modeled by Gaussian orbitals that best fit to the wavefunction obtained by an $ab$ initio DFT supercell calculation (see Appendix E). The distance between atoms is also taken from these simulations. To avoid numerical divergences when $r = 0$, we estimate Eq. (9-11) in reciprocal space following Ref. [29]. The values for the zero field splitting ($\Delta_{es} = 3\Delta$), gap between states $A_1$ and $A_2$ ($4\Delta'$) and mixing term between states $E_{1,2}$ and $E_{x,y}$ ($\Delta''$) are given in Figure 2. As $ab$ initio calculations cannot accurately estimate the nitrogen population $p_N = |\beta|^2$ in the single orbital state $a_1(2)$ (see Appendix A for a definition of parameter $\beta$), we have plotted in Figure 2, the values of the spin-spin interaction as a function of $p_N$. In addition, the solid regions in the figure take into account variations of the relative distance among the three carbons, the nitrogen and the vacancy. The distance between the carbons and the vacancy is increased between 0 and 3%, meanwhile the distance between the nitrogen and the vacancy is decrease between 0 and 4% relative to their excited state configuration (solid lines). This shows how the spin-spin interaction depend on the distance between the atoms.

We emphasize that, contrary to the ground state of the NV center, the splitting between $A_1$ and $A_2$ in the excited state exists because the spin-orbit interaction mixes the spin and spatial parts. In fact, at high temperatures, where the spin-orbit interaction averages out [12], and if the spatial part is given by $|X\rangle\langle X| + |Y\rangle\langle Y|$, it can be checked by looking at Eq. (C2) that only the zero field splitting $\Delta_{es}$ survives from the electronic spin-spin interaction, as confirmed by experiments [12, 24]. In addition, the spin-orbit interaction in the excited state, Eq. (6), can be written as $H_{SO} = i(|X\rangle\langle Y| - |Y\rangle\langle X|) \otimes (|\alpha\alpha\rangle\langle \alpha\alpha| - |\beta\beta\rangle\langle \beta\beta|)$, which also vanishes if the spatial part is given by $|X\rangle\langle X| + |Y\rangle\langle Y|$.

VI. SELECTION RULES AND SPIN-PHOTON ENTANGLEMENT SCHEMES

Group theory tells that transitions are dipole allowed if the matrix element contains the totally symmetric IR, $\langle \varphi_f | \hat{e} | \varphi_i \rangle \supset A_1$. In the case of the NV center ($C_{3v}$), the only non-zero matrix elements are $\langle a | \hat{x} \cdot r | e_x \rangle$ and $\langle a | \hat{y} \cdot r | e_y \rangle$, from which it is straightforward to calculate the selection
rules among the 15 eigenstates given in Table I for the unperturbed center. This is shown in Table III. These matrix elements have been confirmed by our first-principles calculations of these matrix elements in the velocity representation as well as by other authors only for the triplet transition [30]. In addition to the well known triplet-triplet transition [31], transitions are allowed between singlets of different electronic configurations. We remark that the transition between singlet $^1A_1(e^2)$ and singlet $^1E(e^2)$ is not strictly forbidden by group theory to first order, but since both states belong to the same electronic configuration, no dipole moment exists between them and the probability of radiative transition is extremely low. According to our results using wave functions from first-principles calculations (see Appendix E), the ratio between the dipole transition matrix elements associated with the singlet states to those of the triplet states is about $5 \times 10^{-9}$.

The singlet-singlet transition might be allowed by phonons or mixing of the states with singlets of different electronic configurations. Recent experiments by Rogers et al. identified an emission from singlet to singlet[12], which we suggest is related to the $^1E(ae) \rightarrow ^1A_1(e^2)$ transition. The transition $^1A_1(e^2) \rightarrow ^1E(e^2)$ might be possible for the reasons described above, but it is unlikely to be sizable. A recent MBPT calculation supports our conclusion [14]. A suitable experiment to unravel this issue would be to look at the presence of this emission under resonant excitation. In this case, if the state $^1E(ae)$ is above the excited state triplet, the state $^1E(ae)$ will be hardly populated and therefore no singlet-singlet transition should be observed.

Once the selection rules are known for the defect, it is possible to realize interesting applications such as spin-photon entanglement generation [32]. In the case of the NV center, the system can be prepared in the $A_2(ae)$ state. Next, the electron can spontaneously decay to the ground state $^3A_2^-$ by emitting a photon with $\sigma_+$ (right circular) polarization or to the state $^3A_2^+$ by emitting a $\sigma_-$ polarized photon (see Figure 3). As a result, the spin of the electron is entangled with the polarization (spin) of the photon. The implementation of this scheme is sensitive to strain, which will be analyzed in Section VII. However, in Section VIII we recognize that the application of an electric field can be used to overcome some of these issues and facilitate the next step of entangling between two NV centers.

VII. THE EFFECT OF STRAIN

Strain refers to the displacement $\Delta u$ of the atomic positions when the crystal is stretched stretch $\Delta x$ [26]. It is a dimensionless tensor expressing the fractional change under stretching, $e_{ij} = \frac{\partial u_i}{\partial x_j}$, and it can be produced by stress (forces applied to the solid structure), electric field, or temperature
TABLE III: Selection rules for optical transitions between: the triplet excited state \((ae)\) and the triplet ground state \((e^2)\), the singlets \((ae)\) and the singlets \((e^2)\), and the singlet \((a^2)\) and the singlets \((ae)\). Linear polarizations are represented by \(\hat{x}\) and \(\hat{y}\), while circular polarizations are represented by \(\hat{\sigma}_+ = \hat{x} \pm i\hat{y}\). As an example, a photon with \(\sigma_+\) polarization is emitted when the electron decays from state \(A_2(ae)\) to state \(^3A_2-(e^2)\).

<table>
<thead>
<tr>
<th>(3A_2^-)</th>
<th>(A_1)</th>
<th>(A_2)</th>
<th>(E_1)</th>
<th>(E_2)</th>
<th>(E_x)</th>
<th>(E_y)</th>
</tr>
</thead>
<tbody>
<tr>
<td>(\sigma_+)</td>
<td>(\hat{x})</td>
<td>(\hat{y})</td>
<td>(\hat{x})</td>
<td>(\hat{y})</td>
<td></td>
<td></td>
</tr>
<tr>
<td>(3A_2)</td>
<td>(\hat{y})</td>
<td>(\hat{x})</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>(3A_2^+)</td>
<td>(\sigma_-)</td>
<td>(\sigma_-)</td>
<td>(\sigma_+)</td>
<td>(\sigma_+)</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

\[ \epsilon_r = \frac{l_r}{\hbar} \sum_e \chi_e^* R_e^\dagger \epsilon R_e. \] (12)

In Appendix [3] we show in detail how to determine the effect of strain on the eigenstates of the defect. For simplicity, in the case of the NV center we only write the effect of strain in the manifold \(\{e_x, e_y, a\}\),

\[ H_{\text{strain}} = \delta_{A1}^a A_1^a + \delta_{A1}^b A_1^b + \delta_{E1}^a E_1^a + \delta_{E2}^a E_2^a + \delta_{E1}^b E_1^b + \delta_{E2}^b E_2^b \] (13)

where \(\delta_{A1}^a = (e_{xx} + e_{yy})/2, \delta_{A1}^b = e_{zz}, \delta_{E1}^a = (e_{xx} - e_{yy})/2, \delta_{E2}^a = (e_{xy} + e_{yx})/2, \delta_{E1}^b = (e_{xz} + e_{zx})/2, \delta_{E2}^b = (e_{yz} + e_{zy})/2\) and

\[ A_1^a = \begin{pmatrix} 1 & 0 & 0 \\ 0 & 1 & 0 \\ 0 & 0 & 0 \end{pmatrix}, \quad E_1^a = \begin{pmatrix} 1 & 0 & 0 \\ 0 & -1 & 0 \\ 0 & 0 & 0 \end{pmatrix}, \quad E_2^a = \begin{pmatrix} 0 & 1 & 0 \\ 1 & 0 & 0 \\ 0 & 0 & 0 \end{pmatrix} \] (14)

\[ A_1^b = \begin{pmatrix} 0 & 0 & 0 \\ 0 & 0 & 0 \\ 0 & 0 & 1 \end{pmatrix}, \quad E_1^b = \begin{pmatrix} 0 & 0 & 1 \\ 0 & 0 & 0 \\ 1 & 0 & 0 \end{pmatrix}, \quad E_2^b = \begin{pmatrix} 0 & 0 & 0 \\ 0 & 0 & 1 \\ 0 & 1 & 0 \end{pmatrix}, \]

in the manifold \(\{e_x, e_y, a\}\). The effect of strain on the orbitals \(a, e_x, e_y\) is easy to see. \(A_1^a\) will shift equally the energies of the states \(e_x\) and \(e_y\), while \(A_1^b\) will shift the energy of states \(a\). Note
that both describe axial stress: the former leaves the $e^2$ electronic configuration unaffected and the latter leaves the $ea$ configuration unaffected. Either one produces relative shifts between both configurations, resulting in an inhomogeneous broadening of the optical transitions. However, they do not change the selection rules. Only the stress $A^a_1 + A^b_1$, corresponding to either expansion or contraction, leaves all relative energies unaffected. $E^a_x$ splits the energy between $e_x$ and $e_y$ and $E^a_y$ mixes the two states. Finally, $E^b_x$ and $E^b_y$ mixes the states $e_x$ and $a_1$ and $e_y$ and $a_1$, respectively.

In the case of the NV center, the effect of the matrices $E^b_{x,y}$ can be neglected thanks to the large gap between orbitals $a$ and $e_{x,y}$. Therefore, in what follows we do not consider them further.

Recent work has been done to analyze how strain affects the excited state structure of the NV center \[10, 12\]. Here we derive the explicit form of strain affecting the different electronic configurations and look at how strain affects the selection rules described in Section VI.

The relevant strain matrices we will consider are $E^a_x$ and $E^a_y$, for which the Hamiltonian is,

$$H_{\text{strain}} = \delta^a_{E_1} (|e_x\rangle\langle e_x| - |e_y\rangle\langle e_y|) + \delta^b_{E_2} (|e_x\rangle\langle e_y| + |e_y\rangle\langle e_x|). \tag{15}$$

This mostly affects the singlet and excited state configurations in the following form,

$$
\begin{pmatrix}
\delta^a_{E_1} & -i\delta^b_{E_2} \\
-i\delta^b_{E_2} & \delta^a_{E_1}
\end{pmatrix}
\begin{pmatrix}
\delta^a_{E_1} & -i\delta^b_{E_2} \\
-i\delta^b_{E_2} & \delta^a_{E_1}
\end{pmatrix}
\begin{pmatrix}
2\delta^a_{E_1} \\
2\delta^b_{E_2}
\end{pmatrix}
\begin{pmatrix}
\delta^a_{E_1} \\
\delta^b_{E_2}
\end{pmatrix}, \tag{16}
$$

for the manifolds $\{A_1, A_2, E_x, E_y, E_1, E_2\}$, $\{^1E_1, ^1E_2, ^1A_1\}$ and $\{^1E_x, ^1E_y\}$, respectively. The ground state, due to its antisymmetric combination between $e_x$ and $e_y$, is stable under the perturbation $H_{\text{strain}}$. This can be checked by applying Eq. (15) to the ground state given in Table I. The effect on the excited state triplet can be seen in Figure 4a, where the unperturbed states are mixed in such a way that, in the limit of high strain, the excited triplet structure splits into two triplets with spatial wavefunctions $E_x$ and $E_y$. When strain overcomes the spin-orbit interaction ($\delta^a_{E_1} > 5.5 \text{ GHz}$), the spin part decouples from the spatial part and the total angular momentum is no longer a good quantum number. Transitions from the excited state triplet to the ground state triplet are linearly polarized, where the polarization indicates the direction of strain in the $xy$ plane.

Figure 4b shows how the polarization of the emitted photon from the state $A_2$ to the ground state $^3A_{2-}$, varies from circular to linear as a function of strain. In the case of $\delta^b_{E_2}$ strain, the
effect is similar but now the mixing is different. As shown in Figure 4, $A_2$ mixes with $E_1$ and the photons become polarized along $x - y$. Note that, in the limit of low strain, in both cases the polarization remains right circularly polarized for the transition between the excited state $A_2(\text{ae})$ to the ground state $^3A_2^-(e^2)$, while the polarization remains left circular for the transition between the excited state $A_2(\text{ae})$ to the ground state $^3A_2^+(e^2)$. The fact that at lower strain the character of the polarization remains circular has been successfully used in entanglement schemes [7]. The polarization properties of the states $E_{1,2}$ are similar to those of the states $A_{1,2}$ but with the opposite polarization.

VIII. STRAIN AND ELECTRIC FIELD

The application of an electric field to a defect leads to two main effects. The first effect, the electronic effect, consists of the polarization of the electron cloud of the defect, and the second one, the ionic effect, consists of the relative motion of the ions. It has been shown that the two effects are indistinguishable, as they have the same symmetry properties [35]. The ionic effect is related to the well-known piezoelectric effect. When a crystal is under stress, a net polarization $P_i = d_{ijk}\sigma_{jk}$ is induced inside the crystal, where $d_{ijk}$ is the third-rank piezoelectric tensor and $\sigma_{jk}$ represents the magnitude and direction of the applied force. Conversely, the application of an electric field might induce strain given by $\epsilon_{jk} = d_{ijk}E_i$, where $E_i$ are the components of the electric field [33]. The tensor $d_{ijk}$ transforms as the coordinates $x_ix_jx_k$ and, therefore, group theory can be used to establish relations between its components for a given point group. In particular, the non-zero components should transform as the irreducible representation $A_1$. By projecting $d_{ijk}$ (or $x_ix_jx_k$) onto the irreducible representation $A_1$, we can determine the non-zero free parameters of the tensor $d$ and determine the effect of electric field on the eigenstates of the unperturbed defect (see Appendix D). In the case of the NV center, the effect on the excited state triplet is given by the following matrix,

$$H_E = g(b + d)E_z + ga 
\begin{pmatrix}
E_x & -iE_y \\
-iE_y & E_x \\
E_x & E_y \\
E_y & -E_x \\
E_x & iE_y \\
iE_y & E_x
\end{pmatrix}
\begin{pmatrix}
E_x & -iE_y \\
-iE_y & E_x \\
E_x & E_y \\
E_y & -E_x \\
E_x & iE_y \\
iE_y & E_x
\end{pmatrix},
(17)$$
in the basis \{A_1, A_2, E_x, E_y, E_1, E_2\}, while the effect on the ground state triplet is

\[ H_E = 2gbE_z, \] (18)

in the basis \{3A_2^+, 3A_2^0, 3A_2^-\}. The parameters \(a\), \(b\) and \(d\) are the components of the piezo electric tensor \(d_{ijk}\) and \(g\) is the coupling between the strain tensor \(e\) and the NV center. Comparing Eq. (17) and (18), we note that the linear response of the excited state and ground state are in principle different. An electric field along the \(\hat{z}\) (NV-axis) can be used to tune the optical transition without distorting the \(C_{3v}\) symmetry of the defect, provided \(b \neq d\). In Figure 5a, we show the linear response of NV centers under an electric field parallel to the NV-axis. In this case, the linearity is not affected by the presence of strain. Our estimates for the ionic effect, based on the response of the lattice defect to electric field and the response of the orbital energies to strain (see Appendix D), indicate that the relative shift between the ground and excited state is about 4 GHz / MV/m. This could be very important in schemes to entangle two NV centers optically as the wavelength of the photons emitted from each NV center need to overlap [36]. In addition, an electric field with components \(E_x, E_y\) can be used to completely restore the \(C_{3v}\) character of the defect. In Figure 5b, we show the response of optical transitions under an electric field perpendicular to the NV axis. In this case, the response is linear if strain is absent and quadratic if strain is non-zero. Dashed lines show the response to an electric field when the defect experiences a 0.3 GHz strain along the [01-1] axis. Our estimations can be used to interpret the Stark shift observations by Tamarat et al. [37].

IX. CONCLUSIONS

We have used group theory to identify, analyze and predict the properties of NV centers in diamond. This analysis can be extended to other deep defects in solids. A careful analysis of the properties of a defect using group theory is essential for predicting spin-photon entanglement generation and for controlling the properties of NV centers in the presence of perturbations such as undesired strain. We have shown that group theoretical approaches can be applied to determine the ordering of the singlets in the \((e^2)\) electronic configuration and to understand the effect of spin-orbit, spin-spin and strain interactions.

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Appendix A: Dangling bond representation and character table

In this appendix we show in detail how to find the electronic representation for the case of the NV center. The NV center contains a vacancy that results in broken bonds in the system. In the tight binding picture, this means that three C atoms and one N-atom do not have enough immediate neighbor atoms to form a covalent bond for each of their valence electrons. These unpaired electrons are called 'dangling bonds'. In the case of the NV center, we consider a simple model consisting of four $sp^3$ dangling bonds, where three of them are centered on each of the three carbon atoms around the vacancy and the fourth dangling bond is associated with the nitrogen atom. The point group symmetry is $C_{3v}$ and its elements are the identity, rotations around the $z$ (NV-axis) by $\pm 2\pi/3$ and three vertical reflection planes where each contains one of the carbons and the nitrogen.

As discussed in Section II, it is possible to construct the representation of the dangling bonds for the point group they belong to. Consider Figure 6 where the $\hat{z}$ axis is pointing out of the paper. The dangling bonds $\{\sigma_1, \sigma_2, \sigma_3, \sigma_N\}$ transform into one another under the operations of the $C_{3v}$ group. In this representation, each operation can be written as a 4 by 4 matrix, as shown in Figure 6. As representations depend on the particular choice of basis, it is customary to designate them using the trace of each matrix (characters). Note that the character for matrices belonging to the same class is the same, so in short the character representation for the dangling bonds is $\Gamma_\sigma = \{412\}$. This representation is clearly reducible, as it can be decomposed by the irreducible representation of the $C_{3v}$ group given in Table IV [38].

Application of Eq. (1) gives the following combination of $\sigma'$s:

$$a_C = (\sigma_1 + \sigma_2 + \sigma_3) / 3, e_x = (2\sigma_1 - \sigma_2 - \sigma_3) / \sqrt{6}, e_y = (\sigma_2 - \sigma_3) \sqrt{2}, a_N = \sigma_N,$$

where $a_C$ and $a_N$ transform as the totally symmetric irreducible representation $A_1$, and $e_x$ and $e_y$ transform as functions of the IR $E$. Note that the $e$ states transform as vectors in the plane perpendicular to the NV axis.

Next, we model the electron-ion interaction to find out the ordering of these states. This interaction can be written in the basis of the dangling bonds $\sigma_i$ as,

$$V = v_n|\sigma_N\rangle\langle \sigma_N| + \sum_i v_i|\sigma_i\rangle\langle \sigma_i| + h_n|\sigma_N\rangle\langle \sigma_N| + \sum_{i>j} |\sigma_i\rangle\langle \sigma_j|h_c \tag{A1}$$
TABLE IV: Character and bases table for the double $C_{3v}$ group. Examples of functions that transform under a particular representation are $\{z, x^2 + y^2, z^2\}$, which transform as the IR $A_1$, the rotation operator $R_z$ as $A_2$, and the pair of functions $\{(x, y), (R_x, R_y), (xy, x^2 - y^2), (yz, xz)\}$ as $E$. The spin projections $\{\alpha(\uparrow), \beta(\downarrow)\}$ transform as the IR $E_{1/2}$ (or $D_{1/2}$), while the functions $\alpha\alpha + i\beta\beta$ and $\alpha\alpha - i\beta\beta$ transform as the IRs $1E_{3/2}$ and $2E_{3/2}$, respectively.

<table>
<thead>
<tr>
<th>$C_{3v}$</th>
<th>$E$</th>
<th>$C_3$</th>
<th>$3\sigma_v$</th>
<th>$\bar{E}$</th>
<th>$2\bar{C}_3$</th>
<th>$3\bar{\sigma}_v$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$A_1$</td>
<td>1</td>
<td>1</td>
<td>1</td>
<td>1</td>
<td>1</td>
<td>1</td>
</tr>
<tr>
<td>$A_2$</td>
<td>1</td>
<td>1</td>
<td>-1</td>
<td>1</td>
<td>1</td>
<td>1</td>
</tr>
<tr>
<td>$E$</td>
<td>2</td>
<td>-1</td>
<td>0</td>
<td>2</td>
<td>-1</td>
<td>0</td>
</tr>
<tr>
<td>$E_{1/2}$</td>
<td>2</td>
<td>1</td>
<td>0</td>
<td>-2</td>
<td>-1</td>
<td>0</td>
</tr>
<tr>
<td>$1E_{3/2}$</td>
<td>1</td>
<td>-1</td>
<td>$i$</td>
<td>-1</td>
<td>1</td>
<td>$-i$</td>
</tr>
<tr>
<td>$2E_{3/2}$</td>
<td>1</td>
<td>-1</td>
<td>$-i$</td>
<td>-1</td>
<td>1</td>
<td>$i$</td>
</tr>
</tbody>
</table>

where $v_i < 0$ is the Coulomb interaction of orbital $\sigma_i$ at site $i$, $h_c$ is the expectation value of the interaction between orbitals $\sigma_i$ and $\sigma_{i+1}$ at site $i = \{1, 2, 3\}$, $v_n = \langle \sigma_N|V|\sigma_N \rangle$ and $h_n = \langle \sigma_i|V|\sigma_N \rangle$. This interaction, which transforms as the totally symmetric IR $A_1$, not only sets the order of the orbitals but also mixes orbitals $a_N$ and $a_C$. This is a consequence of the important concept that whenever a matrix element contains the totally symmetric representation, its expectation value might be different from zero \cite{16}. Since both wave functions as well as the interaction between them transform as the totally symmetric representation $A_1$, the representation for the matrix element also transform as $A_1$: $\Gamma(\langle \rangle) = \Gamma_a \otimes \Gamma_{\sigma_N} \otimes \Gamma_{int} = A_1 \supset A_1$. This interaction leads to the new basis \cite{19} $\{a_1(1) = \alpha a_c + \beta a_n, a_1(2) = \alpha a_n + \beta a_c, e_x = (2\sigma_1 - \sigma_2 - \sigma_3)/\sqrt{6}, e_y = (\sigma_2 - \sigma_3) \sqrt{2}\}$, with energies $\{E_{a_1(1)},a_1(2)\} = 1/2(v_c + 2h_c + v_n) \pm 1/2\Delta, v_c - h_c, v_c - h_c\}$, respectively, where $\Delta = \sqrt{(v_c + 2h_c - v_n)^2 + 12h_n^2}$, $\alpha^2 = 1 - \beta^2 = 3h_n^2/\Delta E_{a_1(1)}$. We see that the most symmetric state is lowest in energy, which is usually the case for attractive interactions.

Appendix B: Ordering of singlet states

Here we show that two states belonging to the same irreducible representation should have the same expectation value for their Coulomb interaction. We first note that the expectation value of an operator is a scalar and it should not depend on the particular coordinate system in use. In particular, this expectation value should be invariant under any operation of the $C_{3v}$ group of the NV center. The Coulomb interaction is totally symmetric and therefore not affected by any
rotation, and the wavefunctions \( \{e_x, e_y\} \) transform as the irreducible representation \( E \). Therefore, we can get more information about these expectation values by projecting them on the totally symmetric irreducible representation \( A_1 \),

\[
(ab, V, cd) = \frac{1}{\hbar} \sum_{R=1}^{h} \chi_e (P_R(a)P_R(b), V, P_R(c)P_R(d)). \tag{B1}
\]

We find as expected that

\[
\langle 1E_1, V, 1E_1 \rangle = \frac{1}{2}\langle 1E_1, V, 1E_1 \rangle + \frac{1}{2}\langle 1E_2, V, 1E_2 \rangle, \tag{B2}
\]

which means that the states \( (1E_1, V, 1E_1) \) and \( (1E_2, V, 1E_2) \) have the same energy, as required by symmetry.

**Appendix C: Spin-spin interaction**

In order to analyze the effect of spin-spin interactions (Eq. 7) from the perspective of group theory, we first rewrite this interaction to identify spatial and spin terms that transform as IR objects in the point group.

\[
h_{ss} = -\frac{\mu_0 g^2 \beta^2}{4\pi} \left[ \frac{1 - 3\hat{z}^2}{4r^3} (s_{1+}s_{2-} + s_{1-}s_{2+} - 4s_1z_s2z) 
+ \frac{3\hat{x}\hat{y}}{4} (s_{1-}s_{2-} + s_{1+}s_{2+}) 
+ \frac{3\hat{x}\hat{z}}{2} (s_{1-}s_{2+} + s_{1z}s_{2-} + s_{1+}s_{2z} + s_{1z}s_{2+}) 
+ \frac{3\hat{y}\hat{z}}{2} (s_{1-}s_{2+} + s_{1z}s_{2-} - s_{1+}s_{2z} - s_{1z}s_{2+}) \right],
\]

where \( \hat{x}, \hat{y}, \hat{z} \) are directional cosines and \( s_{\pm} = s_x \pm is_y \). In the case of \( C_{3v} \), for the unperturbed center, the expectation values of the 4th and 5th terms are nonzero in the spatial manifold of the excited state \( \{|X\rangle, |Y\rangle\} \) because the center lacks inversion symmetry. However, these terms might be neglected when considering other defects with inversion symmetry. We note now that the spatial part of the first term transforms as the totally symmetric representation \( A_1 \), while the 2nd and 3rd terms transform as the irreducible representation \( E \). The reader can check which IR these combinations belong to by looking at the character table in the Appendix. Therefore, their expectation values can be written as

\[
\frac{\mu_0 g^2 \beta^2}{4\pi} \left[ \frac{1 - 3\hat{z}^2}{4r^3} \right] = \Delta (|X\rangle\langle X| + |Y\rangle\langle Y|) \]
\[ \frac{\mu_0}{4\pi} g^2 \beta^2 \left( \frac{3\hat{x}^2 - 3\hat{y}^2}{4r^3} \right) = \Delta'(\langle X|X\rangle - |Y\rangle\langle Y|) \]  
\[ \frac{\mu_0}{4\pi} g^2 \beta^2 \left( \frac{3\hat{x}\hat{y} + 3\hat{y}\hat{x}}{4r^3} \right) = \Delta'(\langle X|Y\rangle + |Y\rangle\langle X|), \]
\[ \frac{\mu_0}{4\pi} g^2 \beta^2 \left( \frac{3\hat{x}\hat{z} + 3\hat{z}\hat{x}}{4r^3} \right) = \Delta''(\langle Y|Y\rangle - |X\rangle\langle X|), \]
\[ \frac{\mu_0}{4\pi} g^2 \beta^2 \left( \frac{3\hat{y}\hat{z} + 3\hat{z}\hat{y}}{4r^3} \right) = \Delta''(\langle X|Y\rangle + |Y\rangle\langle X|), \]

where \(|X\rangle \) and \(|Y\rangle \) are the two electron states given in Table I. Note that, for symmetry reasons, the second and third relations are characterized by the same parameter \(\Delta'\), while the last two relations are characterized by the same parameter \(\Delta''\). Similarly, it is possible to write the spin operators in the spin basis of the two holes, \(|\alpha\alpha\rangle, |\alpha\beta\rangle, |\beta\alpha\rangle, |\beta\beta\rangle\). For example, \(s_1^+s_2^- = |\alpha\beta\rangle\langle \beta\alpha|\). Using these relations and Eq. (C1), the Hamiltonian in the fundamental bases of the excited state of the NV center is

\[
H_{ss} = -\Delta(|X\rangle\langle X| + |Y\rangle\langle Y|)
\]
\[
\otimes (|\alpha\alpha\rangle\langle \alpha\alpha| + |\beta\beta\rangle\langle \beta\beta| - 2|\alpha\beta + \beta\alpha\rangle\langle \alpha\beta + \beta\alpha|)
\]
\[
-\Delta'(|X\rangle\langle X| - |Y\rangle\langle Y|) \otimes (|\alpha\alpha\rangle\langle \beta\beta| + |\beta\beta\rangle\langle \alpha\alpha|)
\]
\[
-i\Delta'(|X\rangle\langle Y| + |Y\rangle\langle X|) \otimes (|\beta\beta\rangle\langle \alpha\alpha| - |\alpha\alpha\rangle\langle \beta\beta|)
\]
\[
+ \Delta''(|Y\rangle\langle Y| - |X\rangle\langle X|)
\]
\[
\otimes (|\alpha\beta + \beta\alpha\rangle\langle \alpha\alpha - \beta\beta| + |\alpha\alpha - \beta\beta\rangle\langle \alpha\beta + \beta\alpha|)
\]
\[
+ i\Delta''(|Y\rangle\langle Y| - |X\rangle\langle X|)
\]
\[
\otimes (|\alpha\beta + \beta\alpha\rangle\langle \alpha\alpha + \beta\beta| - |\alpha\alpha + \beta\beta\rangle\langle \alpha\beta + \beta\alpha|).
\]

Finally, we can write \(H_{ss}\) in terms of the eigenstates of the unperturbed defect (see Table I). This leads to Eq. (8).

Appendix D: Strain and electric field

The effect of strain on the electronic structure of the defect can be obtained from the effect of the electron-nuclei Coulomb interaction on the eigenstates of the defect. In our example, the Coulomb interaction is given by Eq. (A1). However, when the positions of the atoms are such that the symmetry of the defect is reduced, we should allow for different expectation values of the matrix elements: \(h_{ij} = \langle \sigma_i|V|\sigma_j\rangle\) and \(h_{in} = \langle \sigma_i|V|\sigma_N\rangle\). We have assumed that the self interactions, \(v_c\) and \(v_n\), do not change as the electrons follow the position of the ion according to the Born Oppenheimer
approximation. To relate the matrix elements to the ionic displacements, we can assume as a first
approximation that the electron orbitals are spherical functions, and therefore the matrix elements
can be parametrized by the distance between ions, $h_{ij} (q_i, q_j) = h_{ij} (|q_i - q_j|)$, so that we can write
\[
h_{ij} (|q_{ij}|) \approx h_{ij} \left( |q_{ij}| \right) + \frac{1}{|q_{ij}|} \frac{\partial h_{ij}}{\partial q_{ij}} (q_i - q_j) \cdot (\delta q_i - \delta q_j) + \ldots. \tag{D1}
\]
The change in the matrix elements is linear in the atomic displacements. In turn, the atomic
displacements are related to the strain tensor by $\delta q_i = e q_i$, and therefore the change in the matrix
element is given by
\[
\delta h_{ij} (|q_{ij}|) \approx \frac{1}{|q_{ij}|} \frac{\partial h_{ij}}{\partial q_{ij}} (q_i - q_j)^T e (q_i - q_j). \tag{D2}
\]
Under these considerations, it is straightforward to calculate the effect of strain on the eigenstates
of the defect. For simplicity, we write here only the effect of strain on the degenerate orbitals, $e_x$
and $e_y$,
\[
\delta V = -g \begin{pmatrix} e_{xx} & e_{xy} \\ e_{xy} & e_{yy} \end{pmatrix}, \tag{D3}
\]
where $g = \frac{8 q}{3} \frac{\partial h_{ij}}{\partial q_{ij}}$ and $q$ is the nearest neighbor distance between atoms. Using the electron
wavefunction obtained from \textit{ab initio} calculations (see Appendix E) we estimate that $g \approx 2$ PHz
($P = \text{peta} = 10^{15}$).

The effect of electric field on the eigenstates of the defect can be analyzed by the inverse
piezoelectric effect as described in Section VIII. In this appendix we show how group theory can
tell us the nature of the piezoelectric tensor. By projecting $d_{ijk}$ (or $x_i x_j x_k$) onto the irreducible
representation $A_1$, we can build the following relations,
\[
a = d_{111} = -d_{221} = -d_{122} = d_{333} \quad d = d_{333} \tag{D4}
\]
\[
b = d_{113} = d_{223} \quad c = d_{131} = d_{232} \tag{D5}
\]
and the $d$ tensor can be written in the following short notation (contracted matrix form)\[33\]
\[
d_{ijk} \rightarrow \begin{pmatrix} a & -a & c \\ c & -2a \\ b & b & d \end{pmatrix}. \tag{D6}
\]
For a given electric field, we have a strain tensor of the form
\[
\epsilon = \begin{pmatrix} aE_x + bE_z & -aE_y & cE_x \\ -aE_y & -aE_x + bE_z & cE_y \\ cE_x & cE_y & dE_z \end{pmatrix}. \tag{D7}
\]
To evaluate the magnitude of the piezo-electric response, we have used first-principles calculations as described in Appendix E. The values for the components of the piezo-electric tensor due to ionic effect are \( a \approx b \approx c \approx 0.3 \, \mu \text{MV/m}^{-1} \) and \( d \approx 3 \, \mu \text{MV/m}^{-1} \).

Appendix E: Information about the first principles methods applied in our study

To determine the values of the constants \( a, b, c \) and \( d \) introduced in Appendix D, we applied density functional theory (DFT) [39] calculations within a generalized gradient approximation PBE (Perdew-Burke-Ernzerhof) [40]. In the study of spin-orbit and spin-spin interactions we used a 512-atom supercell to model the negatively charged nitrogen-vacancy defect in diamond. Particularly, we utilized the VASP code [41, 42] to determine the geometry of the defect which uses the projector augmented wave method [43, 44] to eliminate the core electrons, while a plane wave basis set is employed for expanding the valence wavefunctions. We applied the standard VASP projectors for the carbon and nitrogen atoms with a plane wave cut-off of 420 eV. The geometry optimization was stopped when the magnitude of the forces on the atoms was lower than 0.01 eV/Å. We calculated the geometry of both ground and excited states. We applied the constrained DFT method to calculate the charge density of the excited state, that is, by promoting one electron from the \( a_1(2) \) orbital to the \( e_x, e_y \) orbitals as explained in Refs. [25, 45]. This procedure is a relatively good approximation as confirmed by a recent many-body perturbation theory study [14]. The obtained geometries from VASP calculations were used as starting points in the calculations of spin-orbit and spin-spin interactions.

The spin-orbit energy was calculated by following Eq. (4) in our manuscript. Since the spin-orbit interaction is short-range, we applied all-electron methods beyond the frozen-core approximation. We utilized the CRYSTAL code [46] for this calculation using the PBE functional within DFT. We took the geometry as obtained from the VASP calculation. We applied 6-31*G Gaussian basis set for both the carbon and nitrogen atoms. The calculated properties (like the position of the defect levels in the gap) agreed well with those from plane-wave calculations. We obtained the all-electron single particle states and the corresponding Kohn-Sham potentials on a grid and calculated the spin-orbit energy numerically.

Finally, we also studied the piezo-electric effect. In this case an external electric field was applied along the NV-axis and perpendicular to it. For this investigation only a finite size model can be used, thus we modeled the negatively charged nitrogen-vacancy defect in a molecular cluster consisting of 70 carbon atoms and one nitrogen atom. The defect was placed in the middle of the
cluster. The surface dangling bonds of the cluster were terminated by hydrogen atoms. In our previous studies we showed [19] that the defect wave functions are strongly localized around the core of the defect, thus our cluster model can describe reasonably well the situation occurring in the bulk environment. For this investigation we again applied DFT with the PBE functional as implemented in the SIESTA code [47]. We used the standard double-$\zeta$ polarized basis set and Troullier-Martins norm-conserving pseudopotentials [48]. This method gives identical results with those obtained from plane wave calculations regarding the geometry and the wave functions in supercell models [19]. We fully optimized the defective nanodiamond with and without the applied electric field. In this case we applied a very strict limit to the maximum magnitude of forces on the atoms, 0.005 eV/Å. We applied 6 different values of the external electric field along the NV-axis and in perpendicular directions to it, where we could clearly detect the slope of the curvature of atomic displacements versus the applied electric field. The resulting values for the atom displacements in the presence of 1 MV/m electric field are on the order of a few 0.1 µÅ.


[27] The contact term does not contribute due to the Pauli exclusion principle.

[28] Recently, this was indirectly experimentally confirmed. The lower energy state $A_1$ was observed to have a shorter lifetime than the state $A_2$[17]. This is as expected since the state $A_1$ decays non-radiatively to the singlet $^1A_1$ via non-axial spin-orbit.


FIG. 1: Energy diagram of the unperturbed nitrogen-vacancy center in diamond. Note that each electronic configuration can contain triplets (left column) as well as singlets (right column) which have been drawn in separated columns for clarity. Red arrows indicate allowed optical transitions via electric dipole moment interactions. The circular arrows between the states $E_{1,2}$ and $E_{x,y}$ represent the mixing due to spin-spin interaction (see Figure 2). Dashed lines indicate possible non-radiate processes assisted by spin-orbit interaction. In the ground state ($e^2$ configuration), the distance between singlets and triplets is equal to the exchange energy of Coulomb interaction ($2e$). The horizontal dashed blue line represents the orbital energy of the ground state (without including spin-spin interaction).
FIG. 2: **Splitting due to spin-orbit and spin-spin interaction in triplet ac.** (a) The axial part of the spin-orbit interaction splits the states \( \{A_1, A_2\}, \{E_x, E_y\} \) and \( \{E_1, E_2\} \) by \( \lambda_z \). The spin-spin interaction splits states with different spin projections and also splits the \( A_1 \) and \( A_2 \) states. Our theory predicts the \( A_2 \) state at higher energy than the \( A_1 \) state and that the states \( (E_1, 2) \) and \( (E_{x,y}) \) are mixed. As the state \( A_1 \) has an additional non-radiative decay channel, it is possible to confirm this finding by measuring the lifetime of the state. Note that the splitting between \( A_1 \) and \( A_2 \) is a direct consequence of spin-orbit mixing the spatial and spin part of the wavefunction. (b) Values for the zero field splitting (3\( \Delta \)), gap between the states \( A_1 \) and \( A_2 \) (4\( \Delta' \)) and mixing term (4\( \Delta'' \)) due to spin-spin interaction in the excited state as a function of the nitrogen population, \( p_N \), in the state \( a_1(2) \). The shadowed areas indicate the possible values for these parameters when the distance between the vacancy and the three carbons is increased between 0 and 3\%, and the distance between the vacancy and the nitrogen is decreased between 0 and 4\% of their excited state configuration. The solid lines correspond to the maximum (minimum) distance between the carbons (nitrogen) and the vacancy.
FIG. 3: Spin-photon entanglement generation. When the NV center is prepared in the excited state $A_2(3E)$, the electron can decay to the ground state $^3A_2$ $m_s = 1$ ($m_s = -1$) by emitting a right (left) circularly polarized photon.

$|A_2⟩ = |E_+⟩ \otimes |ββ⟩ + |E_-⟩ \otimes |αα⟩$

$|^3A_{2-}⟩ = |E_0⟩ \otimes |ββ⟩$

$|E_0⟩ \otimes |αα⟩ = |^3A_{2+}⟩$

FIG. 4: Excited state structure as a function of strain. (a) Eigenvalues of the excited state triplet as a function of $\delta_{E1}^a$ strain. (b) Mixture of the eigenstate with higher energy (corresponding to $A_2$ in the limit of low strain) and (c) the polarization of dipolar radiation under transitions from this state to the $^3A_{2+}$ state of the ground state. Note that in both cases the circular polarization character of radiation remains. On the other hand, the linear polarization rotates $90^\circ$ for strain along $\delta_{E2}^b$ with respect to that of strain along $\delta_{E1}^a$. 
FIG. 5: Piezo-electric response of optical transitions. (a) response to electric field $E_z$ along the NV-axis ($[111]$ orientation or equivalents). The defect only shows linear Stark Shift independent on the initial strain. (b) electric field $E_x$ applied perpendicular to the NV-axis in the absence of strain (solid lines). The optical transitions $^3A_2(m_s = 0) \rightarrow E_x(m_s = 0)$ and $^3A_2(m_s = 0) \rightarrow E_y(m_s = 0)$ are split linearly and evenly. In the presence of strain along the $\hat{y}$ direction (dashed lines), the response is quadratic due to the splitting between $E_x$ and $E_y$ states in the excited state. Our numerical results are in fair agreement with experimental results\cite{37}. 
FIG. 6: Schematic of the NV defect and dangling bond representation. (Top) Schematics of the dangling bond orbitals used to represent the NV defect. The symmetry axis or NV axis is pointing out of the plane of the page. The dashed lines represent the three vertical reflections planes of the $C_3v$ group. (Bottom) Matrix representation of the dangling bonds.